

University	Peter the Great St. Petersburg Polytechnic University
Level of English proficiency	Upper-Intermediate (B2)
Educational program and field of the educational program for which the applicant will be accepted	1.3.5. Physical electronics 1.3.8. Condensed matter physics ENGINEERING & TECHNOLOGY 2.2.3. Technology and equipment for electronics manufacturing
List of research projects of the potential supervisor (participation/leadership)	<ul style="list-style-type: none"> •Development of an operating algorithm and creation of a mock-up of a control unit for optical pollution sensors. Development of a mock-up of a stand for assessing the impact force of water droplets in a nozzle spray torch, with the company Turbotect SPb. (leadership); • Development of ultra-sensitive thin-film sensors based on multilayer nanostructures, with Shanghai MiaoSheng Intelligent Technology Co., Ltd, (leadership); • Implementation of SmartFoil technology in the manufacture of electronics using ceramic, piezoceramic and metal SMD elements, with the company HengE (Shanghai) Medical Technology Co., Ltd (participation); • Development of the technology of using SmartFoil material in the installation of piezoceramic elements with the JSC Concern Central Research Institute Elektropribor (participation); • Development of technology for using SmartFoil material in the installation of piezoceramic elements. Creation of experimental samples of piezoceramic bags fastened using SmartFoil technology with the SRI STT company (participation); • Creation of a series of samples of ‘SmartFoil’ material with the company HengE (Shanghai) Medical Technology Co., Ltd ” (participation)
List of the topics offered for the prospective scientific research	<ul style="list-style-type: none"> •Sensors based on thin-film nanostructures • Carbon nanostructures in electronic engineering • Field emitters based on nanostructured objects • Electrical properties of thin-film nanostructures • Self-organization of nanostructures and their electronic properties

 <p>Research supervisor: Pavel G. Gabdulin PhD in physics and mathematics (<i>Peter the Great St. Petersburg Polytechnic University</i>)</p>	<p><i>Engineering and technology 2.05. Materials engineering Materials science, coatings & films</i></p>
	<p>Supervisor's research interests</p> <p>Surface, thin films, nanostructures, carbon nanostructures, field emission, materials for electronics, thermoelectricity, multilayer nanosystems</p>
	<p>Research highlights</p> <p>Research will be carried out on the basis of unique latest equipment owned by the laboratory "Self-organizing high- temperature nanostructures." The laboratory has equipment that carries out a full cycle of research work: from designing and creating samples of nanostructures (PVD and SVD) to their research using a set of advanced facilities.</p> <p>Graduate students will work in collaboration with:</p> <ul style="list-style-type: none"> • Shanghai Institute of Technical Physics Chinese Academy of Sciences, Shanghai, China; • University of Trieste and Director of CNR-IOM, Italy; • National Academy of Sciences of Belarus, Minsk, Belarus; • Tsinghua University, Beijing, China. <p>Additional funding for graduate students will occur in the framework of many research and development efforts. These works are held in the laboratory regularly.</p>
	<p>Supervisor's specific requirements:</p> <p>Possible areas of preparation:</p> <ul style="list-style-type: none"> • Electronics and Nano-Electronics; • Nanotechnology; • Technical Physics; • Physics; • Physical chemistry; • Instrument making and electronics; • and the like. <p>Background Discipline:</p> <ul style="list-style-type: none"> • General classical physics; • Mathematical analysis; • Probability theory; • Basics of working with electronic devices; • Work in any software packages for modeling and / or design
	<p>Supervisor's main publications</p>

	<ul style="list-style-type: none"> • A.V. Arkhipov, A.M. Zhurkin, O.E. Kvashenkina, V.S. Osipov, P.G. Gabdullin, Electron overheating during field emission from carbon island films due to phonon bottleneck effect // <i>Nanosystems: Physics, Chemistry, Mathematics</i>, 2018, Vol. 9(1), P. 110-113. Основные публикации потенциального научного руководителя DOI 10.17586/2220-8054-2018-9-1-110-113 IF 1.25; http://nanojournal.ifmo.ru/en/wp-content/uploads/2018/02/NPCM91P110-113 .pdf • Andronov, A., Budylna, E., Shkitun, P., Gabdullin, P., Gnuchev, N., Kvashenkina, O., Arkhipov, A. Characterization of thin carbon films capable of low-field electron emission // (2018) <i>Journal of Vacuum Science and Technology B: Nanotechnology and Microelectronics</i>, 36 (2), статья № 02C108, DOI: 10.1116/1.5009906 IF 1.314, SJR2017 0.467; Q2 https://avs.scitation.Org/doi/full/10.1116/1.5009906 • Arkhipov, A.V., Gabdullin, P.G., Gordeev, S.K., Zhurkin, A.M., Kvashenkina, O.E. Photostimulation of conductivity and electronic properties of field-emission nanocarbon coatings on silicon // (2017) <i>Technical Physics</i>, 62 (1), pp. 127-136. DOI: 10.1134/S1063784216120045, IF 0.707, SJR2017 0.390; Q2 https://link.springer.com/article/10.1134/S1063784216120045 • Bizyaev, I.S.; Gabdullin, P.G.; Arkhipov, A.V.; Babyuk, V.Y. Study of surface topography and emission properties of thin Mo and Zr films. (2019) <i>Journal of Physics Conference Series</i>, Vol. 1236, #012019 DOI: 10.1088/1742-6596/1236/1/012019 IF 0.51; Q3 https://iopscience.iop.org/article/10.1088/1742-6596/1236/1/012019 • Osipov, V.S.; Besedina, N.A.; Gabdullin, P.G.; Kvashenkina, O.E.; Arkhipov, A.V. Study of nanocarbon thin-film field-electron emitters by Raman spectroscopy. (2019) <i>Journal of Physics Conference Series</i>, Vol 1236, # 012005.
	<p>Results of intellectual activity</p> <ol style="list-style-type: none"> 1. China patent: CN108265258 date May 08, 2020, The method of producing multilayer reactive nanostructures 2. EUR patent: EAPO 035213 date may 18 2020, The method used to attach PCBs to various materials 3. EUR patent: EAPO 035216 date may 18 2020, The method used for fixing piezoceramic materials in various materials